

DATASHEET

Description

The 9DBL0442 / 9DBL0452 devices are 3.3V members of IDT's Full-Featured PCIe family. The 9DBL0442 / 9DBL0452 supports PCIe Gen1-4 Common Clocked (CC) and PCIe Separate Reference Independent Spread (SRIS) systems. It offers a choice of integrated output terminations providing direct connection to 85Ω or 100Ω transmission lines. The 9DBL04P2 can be factory programmed with a user-defined power up default SMBus configuration.

Recommended Application

PCIe Gen1-4 clock distribution for Riser Cards, Storage, Networking, JBOD, Communications, Access Points

Output Features

- 4 1-200 MHz Low-Power (LP) HCSL DIF pairs
 - 9DBL0442 default Zout = 100Ω
 - 9DBL0452 default Zout = 85Ω
 - 9DBL04P2 factory programmable defaults
- Easy AC-coupling to other logic families, see IDT application note AN-891

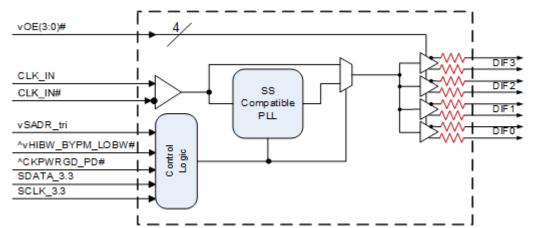
Key Specifications

- PCIe Gen1-2-3-4 CC compliant in ZDB mode
- PCle Gen2 SRIS compliant in ZDB mode
- Supports PCle Gen2-3 SRIS in fan-out mode
- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew < 50ps
- Bypass mode additive phase jitter is 0 ps typical rms for
- Bypass mode additive phase jitter 160fs rms typ. @ 156.25M (1.5M to 10M)

Features/Benefits

- Direct connection to 100Ω (xx42) or 85Ω (xx52) transmission lines; saves 16 resistors compared to standard PCIe devices
- 132mW typical power consumption in PLL mode; eliminates thermal concerns
- · SMBus-selectable features allows optimization to customer requirements:
 - control input polarity
 - control input pull up/downs
 - slew rate for each output
 - differential output amplitude
 - output impedance for each output
 - 50, 100, 125MHz operating frequency
- · Customer defined SMBus power up default can be programmed into P2 device; allows exact optimization to customer requirements
- OE# pins; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- Spread Spectrum tolerant; allows reduction of EMI
- Pin/SMBus selectable PLL bandwidth and PLL Bypass; minimize phase jitter for each application
- Outputs blocked until PLL is locked; clean system start-up
- Device contains default configuration; SMBus interface not required for device operation
- Three selectable SMBus addresses; multiple devices can easily share an SMBus segment
- Space saving 32-pin 5x5mm VFQFPN; minimal board space

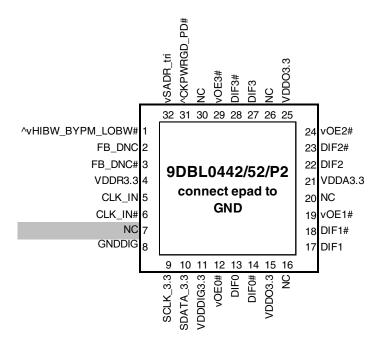
Block Diagram



Note: Resistors default to internal on xx42/xx52 devices. P2 devices have programmable default impedances on an output-by-output basis.



Pin Configuration



32-pin VFQFPN, 5x5 mm, 0.5mm pitch

^ prefix indicates internal 120KOhm pull up resistor ^v prefix indicates internal 120KOhm pull up AND pull down resistor (biased to VDD/2)

v prefix indicates internal 120KOhm pull down resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of	0	1101011	Х
CKPWRGD_PD#	M	1101100	X
	1	1101101	x

Power Management Table

CKPWRGD PD#	CLK IN SMBus OEx#		OEx# Pin	DIFx/D	PLL	
CRFWRGD_FD#	OLK_IN	OE bit	OE bit True O/P		Comp. O/P	FLL
0	Х	Х	Х	Low ¹	Low ¹	Off
1	Running	1	0	Running	Running	On ³
1	Running	1	1	Disabled ¹	Disabled ¹	On ³
1	Running	0	Х	Disabled ¹	Disabled ¹	On ³

- 1. The output state is set by B11[1:0] (Low/Low default)
- 2. Input polarities defined as default values for xx42/xx52 devices.
- 3. If Bypass mode is selected, the PLL will be off, and outputs will be running.

Power Connections

Pin Num	ber	Description		
VDD	GND	Description		
4	33	Input receiver analog		
11	8	Digital Power		
15,25	33	DIF outputs		
21	33	PLL Analog		

PLL Operating Mode

		Byte1 [7:6]	Byte1 [4:3]
HiBW_BypM_LoBW#	MODE	Readback	Control
0	PLL Lo BW	00	00
M	Bypass	01	01
1	PLL Hi BW	11	11



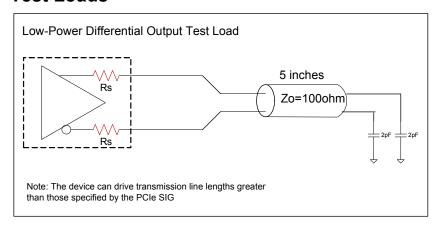
Pin Descriptions

Pin#	Pin Name	Type	Pin Description
			Tri-level input to select High BW, Bypass or Low BW mode. This pin is biased to VDD/2
1	^vHIBW_BYPM_LOB	LATCHED	(Bypass mode) with internal pull up/pull down resistors. See PLL Operating Mode Table for
		IN	Details.
	ED DNO	DNO	True clock of differential feedback. The feedback output and feedback input are
2	FB_DNC	DNC	connected internally on this pin. Do not connect anything to this pin.
_	ED DNO"	5110	Complement clock of differential feedback. The feedback output and feedback input are
3	FB_DNC#	DNC	connected internally on this pin. Do not connect anything to this pin.
	\(\(\tau\)	5345	3.3V power for differential input clock (receiver). This VDD should be treated as an Analog
4	VDDR3.3	PWR	power rail and filtered appropriately.
5	CLK_IN	IN	True Input for differential reference clock.
6	CLK_IN#	IN	Complementary Input for differential reference clock.
7	NC	N/A	No Connection.
8	GNDDIG	GND	Ground pin for digital circuitry
9	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
10	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
11	VDDDIG3.3	PWR	3.3V digital power (dirty power)
			Active low input for enabling output 0. This pin has an internal 120kohm pull-down.
12	vOE0#	IN	1 =disable outputs, 0 = enable outputs
13	DIF0	OUT	Differential true clock output
	DIF0#	OUT	Differential Complementary clock output
	VDDO3.3	PWR	Power supply for outputs,nominal 3.3V.
	NC	N/A	No Connection.
17	DIF1	OUT	Differential true clock output
18	DIF1#	OUT	Differential Complementary clock output
			Active low input for enabling output 1. This pin has an internal 120kohm pull-down.
19	vOE1#	IN	1 =disable outputs, 0 = enable outputs
20	NC	N/A	No Connection.
21	VDDA3.3	PWR	3.3V power for the PLL core.
22	DIF2	OUT	Differential true clock output
23	DIF2#	OUT	Differential Complementary clock output
			Active low input for enabling output 2. This pin has an internal 120kohm pull-down.
24	vOE2#	IN	1 =disable outputs, 0 = enable outputs
25	VDDO3.3	PWR	Power supply for outputs,nominal 3.3V.
	NC	N/A	No Connection.
	DIF3	OUT	Differential true clock output
28	DIF3#	OUT	Differential Complementary clock output
			Active low input for enabling output 3. This pin has an internal 120kohm pull-down.
29	vOE3#	IN	1 =disable outputs, 0 = enable outputs
30	NC	N/A	No Connection.
	110	1 1/ /71	Input notifies device to sample latched inputs and start up on first high assertion. Low
31	^CKPWRGD_PD#	IN	enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin
01		111	has internal 120kohm pull-up resistor.
		LATCHED	Tri-level latch to select SMBus Address. It has an internal 120kohm pull down resistor.
32	vSADR_tri	IN	See SMBus Address Selection Table.
33	epad		connect epad to ground.
	DNC indicates Do Not		

NOTE: DNC indicates Do Not Connect anything to this pin.



Test Loads



Terminations

Device	Ζο (Ω)	Rs (Ω)
9DBL0442	100	None needed
9DBL0452	100	7.5
9DBL04P2	100	Prog.
9DBL0442	85	N/A
9DBL0452	85	None needed
9DBL04P2	85	Prog.

Alternate Terminations

The 9DBL family can easily drive LVPECL, LVDS, and CML logic. See <u>"AN-891 Driving LVPECL, LVDS, and CML Logic with IDT's "Universal" Low-Power HCSL Outputs"</u> for details.



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBL0442 / 9DBL0452. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx				4.6	V	1,2
Input Voltage	V_{IN}		-0.5		V _{DD} +0.5	V	1,3
Input High Voltage, SMBus	V_{IHSMB}	SMBus clock and data pins			3.9	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2500			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Clock Input Parameters

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V _{CROSS}	Cross Over Voltage	150		900	mV	1
Input Swing - DIF_IN	V_{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-SMBus Parameters

 $TA = T_{AMB;}$ Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
SMBus Input Low Voltage	V_{ILSMB}	$V_{DDSMB} = 3.3V$			0.8	V	
SMBus Input High Voltage	V_{IHSMB}	$V_{DDSMB} = 3.3V$	2.1		3.6	V	
SMBus Output Low Voltage	V_{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V_{DDSMB}		2.7		3.6	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{SMB}	SMBus operating frequency			500	kHz	2,3

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 4.6V.

²Slew rate measured through +/-75mV window centered around differential zero

^{2.} The device must be powered up for the SMBus to function.

^{3.} The differential input clock must be running for the SMBus to be active



Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions

 $TA = T_{AMB}$, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTE
Supply Voltage	VDDx	Supply voltage for core and analog	3.135	3.3	3.465	V	
Ambient Operating Temperature	T _{AMB}	Industrial range	-40	25	85	°C	
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus	0.75 V _{DDx}		$V_{DDx} + 0.3$	٧	
Input Low Voltage	V_{IL}		-0.3		0.25 V _{DDx}	V	
Input High Voltage	V_{IHtri}		0.75 V _{DDx}		$V_{DD} + 0.3$	٧	
Input Mid Voltage	V_{IMtri}	Single-ended tri-level inputs ('_tri' suffix)	0.4 V _{DDx}	0.5 V _{DDx}	0.6 V _{DDx}	V	
Input Low Voltage	V_{lLtri}		-0.3		0.25 V _{DDx}	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Input Current	I _{INP}	$\label{eq:VIN} Single-ended inputs \\ V_{IN} = 0 \ V; \ Inputs \ with internal \ pull-up \ resistors \\ V_{IN} = VDD; \ Inputs \ with \ internal \ pull-down \ resistors$	-50		50	uA	
		Bypass mode	1		200	MHz	2
land Francisco	F _{IN}	100MHz PLL mode	60	100.00	140	MHz	2
Input Frequency		50MHz PLL mode	30	50.00	65	MHz	2
		125MHz PLL mode	75	125.00	175	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency PCIe	f _{MODINPCle}	Allowable Frequency for PCIe Applications (Triangular Modulation)	30		33	kHz	
Input SS Modulation Frequency non-PCIe	f _{MODIN}	Allowable Frequency for non-PCIe Applications (Triangular Modulation)	0		66	kHz	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	clocks	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV



Electrical Characteristics-DIF Low-Power HCSL Outputs

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	2	2.8	4	V/ns	1,2,3
Siew rate	dV/dt	Scope averaging on, slow setting	1.2	1.9	3.1	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching		7	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	768	850	mV	7
Voltage Low	V_{LOW}	using oscilloscope math function. (Scope averaging on)		-11	150	1110	7
Max Voltage	Vmax	Measurement on single ended signal using		811	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off) -300 -49			IIIV	7	
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	357	550	mV	1,5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		14	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Current Consumption

 $TA = T_{AMB}$, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	I _{DDA}	VDDA, PLL Mode @100MHz		7	10	mA	
Operating Supply Current	I _{DDDIG}	VDDDIG, PLL Mode @100MHz		3.4	5	mA	
	I _{DDO+R}	VDDO+VDDR, PLL Mode, All outputs @100MHz		30.0	37	mA	
Powerdown Current	I _{DDRPD}	VDDA, CKPWRGD_PD# = 0		0.6	1.0	mA	1
	I _{DDDIGPD}	VDDDIG, CKPWRGD_PD# = 0		3.1	4.3	mA	1
	I _{DDAOPD}	VDDO+VDDR, CKPWRGD_PD# = 0		0.9	1.3	mA	1

¹ Input clock stopped.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.



Electrical Characteristics-Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

TATE TAMB, Supply Voltages per normal operation conditions, Gos Test Estate for Estating Conditions								
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES	
PLL Bandwidth	BW	-3dB point in High BW Mode (100MHz)	2	3.3	4	MHz	1,5	
FLL Balldwidth	DVV	-3dB point in Low BW Mode (100MHz)	1	1.5	2	MHz	1,5	
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain (100MHz)		0.8	2	dB	1	
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1	
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode	-1	0.0	1	%	1,3	
Skow Input to Output	t _{pdBYP}	Bypass Mode, V _T = 50%	2500	3406	4500	ps	1	
Skew, Input to Output	t _{pdPLL}	PLL Mode V _T = 50%	-100	8	100	ps	1,4	
Skew, Output to Output	t _{sk3}	V _T = 50%		21	55	ps	1,4	
Jitter, Cycle to cycle	+.	PLL mode		15	50	ps	1,2	
Sitter, Cycle to Cycle	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		0.1	1	ps	1,2	

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architectures

T_{AMB} = over the specified operating range. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
	t _{iphPCleG1-CC}	PCle Gen 1		23	32	86	ps (p-p)	1,2,3,5
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.6	0.8	3	ps (rms)	1,2,5
Phase Jitter, PLL Mode	t _{jphPCleG2-CC}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		1.7	2.1	3.1	ps (rms)	1,2,5
	t _{jphPCleG3-CC}	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.4	0.48	1	ps (rms)	1,2,5
	t _{jphPCleG4-CC}	PCIe Gen 4 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.4	0.48	0.5	ps (rms)	1,2,5
	t _{jphPCleG1-CC}	PCIe Gen 1		0.0	0.01		ps (p-p)	1,2,5
	t _{jphPCleG2-CC}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.0	0.01		ps (rms)	1,2,4,5
Additive Phase Jitter, Bypass mode		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz or 8-5MHz, CDR = 5MHz)		0.0	0.01	n/a	ps (rms)	1,2,4,5
	t _{jphPCleG3-CC}	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.0	0.01		ps (rms)	1,2,4,5
	t _{jphPCleG4-CC}	PCIe Gen 4 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.0	0.01		ps (rms)	1,2,4,5

¹ Applies to all outputs.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

⁴ All outputs at default slew rate

⁵ The MIN/TYP/MAX values of each BW setting track each other, i.e., Low BW MAX will never occur with Hi BW MIN.

² Based on PCle Base Specification Rev4.0 version 0.7draft. See http://www.pcisig.com for latest specifications.

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ For RMS values additive jitter is calculated by solving the following equation for b [$a^2+b^2=c^2$] where a is rms input jitter and c is rms total jitter.

⁵ Driven by 9FGL0841 or equivalent



Electrical Characteristics-Filtered Phase Jitter Parameters - PCle Separate Reference Independent Spread (SRIS) Architectures⁵

T_{AMB} = over the specified operating range. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
Phase Jitter, PLL Mode	t _{jphPCleG2} - SRIS	PCIe Gen 2 (PLL BW of 16MHz , CDR = 5MHz)		1.2	1.5	2	ps (rms)	1,2
	t _{jphPCleG3} - SRIS	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		n/a		0.5	ps (rms)	1,2,6
Additive Phase Jitter, Bypass mode	t _{jphPCleG2} - SRIS	PCIe Gen 2 (PLL BW of 16MHz , CDR = 5MHz)		0.0	0.01	n/a	ps (rms)	1,2,4
	t _{jphPCleG3} - SRIS	PCIe Gen 3 (PLL BW of 2-4MHz or 2-5MHz, CDR = 10MHz)		0.0	0.01	II/a	ps (rms)	1,2,4,6

¹ Applies to all outputs.

Electrical Characteristics-Unfiltered Phase Jitter Parameters

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

						INDUSTRY		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
Additive Phase Jitter,	t _{jph156M}	156.25MHz, 1.5MHz to 10MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		159		N/A	fs (rms)	1,2,3
Fanout Mode	t _{jph156M12k-}	156.25MHz, 12kHz to 20MHz, -20dB/decade rollover <12kHz, -40db/decade rolloff > 20MHz		363		N/A	fs (rms)	1,2,3

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² Based on PCIe Base Specification Rev3.1a. These filters are different than Common Clock filters. See http://www.pcisig.com for latest specifications.

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ For RMS values, additive jitter is calculated by solving the following equation for b [a/2+b/2=c/2] where a is rms input jitter and c is rms total jitter.

⁵ As of PCIe Base Specification Rev4.0 draft 0.7, SRIS is not currently defined for Gen1 or Gen4.

⁶ This device does not support PCIe Gen3 SRIS in PLL mode. It supports PCIe Gen3 SRIS in bypass mode.

¹Guaranteed by design and characterization, not 100% tested in production.

² Driven by Rohde&Schartz SMA100

³ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]



General SMBus Serial Interface Information

How to Write

- · Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Bl	ock '	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		O	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus Address is Latched on SADR pin. Unless otherwise indicated, default values are for the xx42 and xx52. P2 devices are fully factory programmable.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read O	Index Block Read Operation							
Cor	ntroller (Host)		IDT (Slave/Receiver)							
Т	starT bit									
SI	ave Address									
WR	WRite									
			ACK							
Begi	nning Byte = N									
			ACK							
RT	Repeat starT									
SI	ave Address									
RD	ReaD									
			ACK							
			Data Byte Count=X							
	ACK									
			Beginning Byte N							
	ACK									
		ē	0							
	0	X Byte	0							
	0	×	0							
	0									
	· · · · · · · · · · · · · · · · · · ·		Byte N + X - 1							
N	Not acknowledge									
Р	stoP bit									



SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7				0		
Bit 6	DIF OE3	Output Enable	RW	1	Pin Control	1
Bit 5				0		
Bit 4	DIF OE2	Output Enable	RW	See B11[1:0]	Pin Control	1
Bit 3	DIF OE1	Output Enable	RW	366 D 1 [1.0]	Pin Control	1
Bit 2		Reserved				0
Bit 1	DIF OE0	Output Enable	RW		Pin Control	1
Bit 0		Reserved				0

^{1.} A low on these bits will overide the OE# pin and force the differential output to the state indicated by B11[1:0] (Low/Low default)

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	PLLMODERB1	PLL Mode Readback Bit 1	R	See PLL Operating Mode Table		Latch
Bit 6	PLLMODERB0	PLL Mode Readback Bit 0	R	See FLL Operat	ling wode rable	Latch
Bit 5	PLLMODE SWCNTRL	Enable SW control of PLL Mode	RW	Values in B1[7:6]	Values in B1[4:3]	0
טום	T ELMODE_OWONTRE	Enable 644 control of 1 EE Wode	1 1 1 1	set PLL Mode	set PLL Mode	
Bit 4	PLLMODE1	PLL Mode Control Bit 1	RW ¹	See PLL Operat	ting Mode Table	0
Bit 3	PLLMODE0	PLL Mode Control Bit 0	RW ¹	See FLL Opera	ling wode rable	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01= 0.68V	1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10 = 0.75V	11 = 0.85V	0

^{1.} B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: Slew Rate Control Register

Byte 2	Name	Control Function	Type	0	1	Default	
Bit 7		Reserved				1	
Bit 6	SLEWRATESEL DIF3	Slew rate selection	RW	Slow Setting	Fast Setting	1	
Bit 5	Reserved						
Bit 4	SLEWRATESEL DIF2	Slew rate selection	RW	Slow Setting	Fast Setting	1	
Bit 3	SLEWRATESEL DIF1	Slew rate selection	RW	Slow Setting	Fast Setting	1	
Bit 2		Reserved				1	
Bit 1	SLEWRATESEL DIF0	Slew rate selection	RW	Slow Setting	Fast Setting	1	
Bit 0	Reserved						

Note: See "Low-Power HCSL Outputs" table for slew rates.

SMBus Table: Slew Rate Control Register

Byte 3	Name	Control Function	Туре	0	1	Default	
Bit 7		Reserved				1	
Bit 6		Reserved					
Bit 5	FREQ_SEL_EN	Enable SW selection of frequency	RW	SW frequency change disabled	SW frequency change enabled	0	
Bit 4	FSEL1	Freq. Select Bit 1	RW ¹	00 = 100M,	10 = 125M	0	
Bit 3	FSEL0	Freq. Select Bit 0	RW ¹	01 = 50M, 1	1= Reserved	0	
Bit 2		Reserved				1	
Bit 1	Reserved					1	
Bit 0	SLEWRATESEL FB	Adjust Slew Rate of FB	RW	Slow Setting	Fast Setting	1	

^{1.} B3[5] must be set to a 1 for these bits to have any effect on the part.

Byte 4 is Reserved



SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R		0	
Bit 6	RID2	Revision ID	R	B rev =	0	
Bit 5	RID1		R	D 16V -	0	
Bit 4	RID0		R		1	
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001	- IDT	0
Bit 1	VID1	VENDOR ID	R	0001 = IDT		0
Bit 0	VID0		R		1	

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	RW	00 = FGx, $01 = DBx ZDB/FOB$,		0
Bit 6	Device Type0	Device Type	RW	10 = DMx, 11= DBx FOB		1
Bit 5	Device ID5		RW			0
Bit 4	Device ID4		RW			0
Bit 3	Device ID3	Device ID	RW	000110binar	0	
Bit 2	Device ID2	Device ID	RW	000 i iobiliai	1	
Bit 1	Device ID1		RW	1		0
Bit 0	Device ID0		RW			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	Reserved						
Bit 4	BC4		RW			0	
Bit 3	BC3		RW	Writing to this regist	er will configure how	1	
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0	
Bit 1	BC1		RW	= 8 b	ytes.	0	
Bit 0	BC0		RW			0	

Bytes 8 and 9 are Reserved

SMBus Table: PD_Restore

Byte 10	Name	Control Function	Туре	0	1	Default	
Bit 7	Reserved						
Bit 6	Power-Down (PD) Restore Restore Default Config. In PD RW Clear Config in PD Keep Config in PD						
Bit 5	Reserved						
Bit 4	Reserved						
Bit 3		Reserved				0	
Bit 2	Reserved						
Bit 1	Reserved						
Bit 0		Reserved				0	



SMBus Table: Stop State and Impedance Control

Byte 11	Name			0	1	Default
Bit 7	FB_imp[1]	FB Zout	RW	00=33Ω DIF Zout	10=100Ω DIF Zout	see Note
Bit 6	FB_imp[0]	FB Zout R'		01=85Ω DIF Zout	11 = Reserved	See Note
Bit 5	Reserved					
Bit 4	Reserved					
Bit 3		Reserved				0
Bit 2		Reserved				0
Bit 1	STP[1]	True/Complement DIF Output RW 00 = Low/Low 10 = Hi			10 = High/Low	0
Bit 0	STP[0]	Disable State	RW	01 = HiZ/HiZ	11 = Low/High	0

Note: xx42 = 10, xx52 = 01, P2 = factory programmable.

SMBus Table: Impedance Control

Byte 12	Name	Control Function		0	1	Default
Bit 7	DIF1_imp[1]	DIF3 Zout	RW	00=33Ω DIF Zout	10=100Ω DIF Zout	
Bit 6	DIF1_imp[0]	Dii 3 200t	RW	01=85Ω DIF Zout	11 = Reserved	
Bit 5	Reserved					
Bit 4	Reserved					
Bit 3	DIF0_imp[1]	DIF1 Zout	RW	00=33Ω DIF Zout	10=100Ω DIF Zout	see Note
Bit 2	DIF1_imp[0]	Dii 1 Zout	RW	01=85Ω DIF Zout	11 = Reserved	
Bit 1	Reserved					
Bit 0	Reserved					

Note: xx42 = 10, xx52 = 01, P2 = factory programmable.

SMBus Table: Impedance Control

Byte 13	Name	Control Function	Type	0	1	Default		
Bit 7		Reserved						
Bit 6		Reserved						
Bit 5	DIF3_imp[1]	DIF6 Zout	RW	$00=33_{\varsigma}$ DIF Zout	$10=100_{\varsigma}$ DIF Zout			
Bit 4	DIF3_imp[0]	DIF6 Zout	RW	$01=85_{\varsigma}$ DIF Zout	11 = Reserved	see Note		
Bit 3		Reserved	-			SEE NOIE		
Bit 2		Reserved						
Bit 1	DIF2_imp[1]	DIF4 Zout	RW	$00=33_{\varsigma}$ DIF Zout	$10=100_{\varsigma}$ DIF Zout			
Bit 0	DIF2_imp[0]	DIF4 Zout	RW	$01=85_{\varsigma}$ DIF Zout	11 = Reserved			

Note: xx42 = 10, xx52 = 01, P2 = factory programmable.

SMBus Table: Pull-up Pull-down Control

Byte 14	Name	Control Function	Туре	0	1	Default	
Bit 7	OE1_pu/pd[1]	OE3 Pull-up(PuP)/	RW	00=None	10=Pup	0	
Bit 6	OE1_pu/pd[0] Pull-down(Pdwn) control		RW	01=Pdwn	11 = Pup+Pdwn	1	
Bit 5	Reserved						
Bit 4	Reserved						
Bit 3	OE0_pu/pd[1]	OE1 Pull-up(PuP)/	RW	00=None	10=Pup	0	
Bit 2	OE0_pu/pd[0]	Pull-down(Pdwn) control	RW	01=Pdwn	11 = Pup+Pdwn	1	
Bit 1	Reserved						
Bit 0		Reserved					

Note: xx42 = 10, xx52 = 01, P2 = factory programmable.



SMBus Table: Pull-up Pull-down Control

Byte 15	Name	Control Function	Type	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	OE3_pu/pd[1]	OE6 Pull-up(PuP)/	RW	00=None	10=Pup	0	
Bit 4	OE3_pu/pd[0]	Pull-down(Pdwn) control	RW	01=Pdwn	11 = Pup+Pdwn	1	
Bit 3		Reserved				0	
Bit 2		Reserved				1	
Bit 1	OE2_pu/pd[1]	OE4 Pull-up(PuP)/	RW	00=None	10=Pup	0	
Bit 0	OE2_pu/pd[0]	Pull-down(Pdwn) control	RW	01=Pdwn	11 = Pup+Pdwn	1	

SMBus Table: Pull-up Pull-down Control

Byte 16	Name	Control Function	Type	0	1	Default		
Bit 7		Reserved						
Bit 6		Reserved				Х		
Bit 5	Reserved							
Bit 4	Reserved							
Bit 3	HIBW_BYPM_LOBWpu/pd[1]	HIBW_BYPM_LOBW Pull-up(PuP)/	RW	00=None	10=Pup	1		
Bit 2	HIBW_BYPM_LOBWpu/pd[0]	• • •	RW	01=Pdwn	11 = Pup+Pdwn	1		
Bit 1	CKPWRGD_PD_pu/pd[1]	CKPWRGD_PD Pull-up(PuP)/	RW	00=None	10=Pup	1		
Bit 0	CKPWRGD_PD_pu/pd[0]	Pull-down(Pdwn) control	RW	01=Pdwn	11 = Pup+Pdwn	0		

Note: xx42 = 10, xx52 = 01, P2 = factory programmable.

Bytes 17 is Reserved

SMBus Table: Polarity Control

Byte 18	Name	Control Function	Type	0	1	Default	
Bit 7		Reserved				0	
Bit 6	OE3_polarity Sets OE6 polarity RW Enabled when Low Enabled when				Enabled when High	0	
Bit 5	Reserved						
Bit 4	OE2_polarity	Sets OE4 polarity	RW	Enabled when Low	Enabled when High	0	
Bit 3	OE1_polarity	Sets OE3 polarity	RW	Enabled when Low	Enabled when High	0	
Bit 2		Reserved				0	
Bit 1	OE0_polarity	Sets OE1 polarity	RW	Enabled when Low	Enabled when High	0	
Bit 0		Reserved				0	

SMBus Table: Polarity Control

Byte 19	Name	Control Function	Type	0	1	Default		
Bit 7	Reserved							
Bit 6	Reserved							
Bit 5	Reserved							
Bit 4	Reserved							
Bit 3	Reserved							
Bit 2		Reserved				0		
Bit 1		Reserved				0		
Bit 0	CKPWRGD_PD	Determines CKPWRGD_PD polarity	RW	Power Down when Low	Power Down when High	0		



Marking Diagrams

ICS
L0442BIL
YYWW
COO
LOT

ICS
L0452BIL
YYWW
COO
LOT

ICS
4P2B000I
YYWW
COO
LOT

Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. "YYWW" is the last two digits of the year and week that the part was assembled.
- 4. Line 2: truncated part number
- 5. "I" denotes industrial temperature range device.

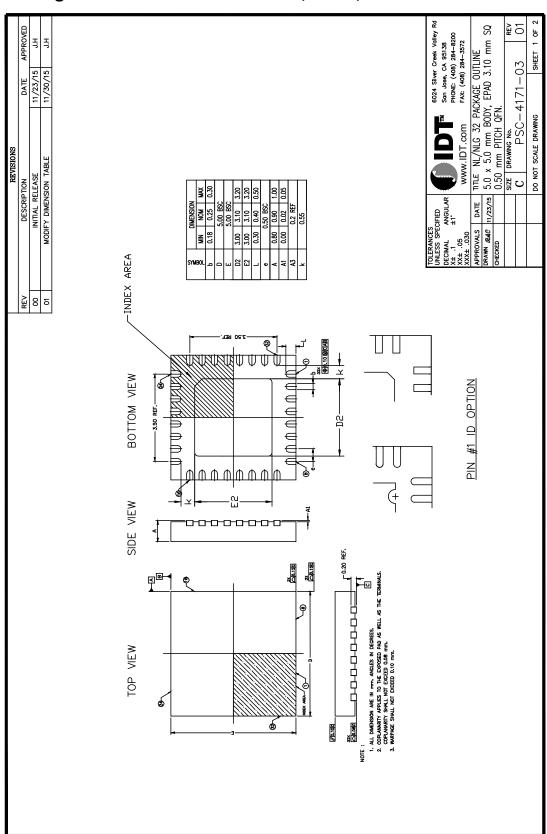
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	θ_{JC}	Junction to Case		42	°C/W	1
	θ_{Jb}	Junction to Base		2.4	°C/W	1
Thermal Resistance	θ_{JA0}	Junction to Air, still air	NLG32	39	°C/W	1
Theimai nesistance	θ_{JA1}	Junction to Air, 1 m/s air flow	INLUSZ	33	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow	_	28	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		27	°C/W	1

¹ePad soldered to board

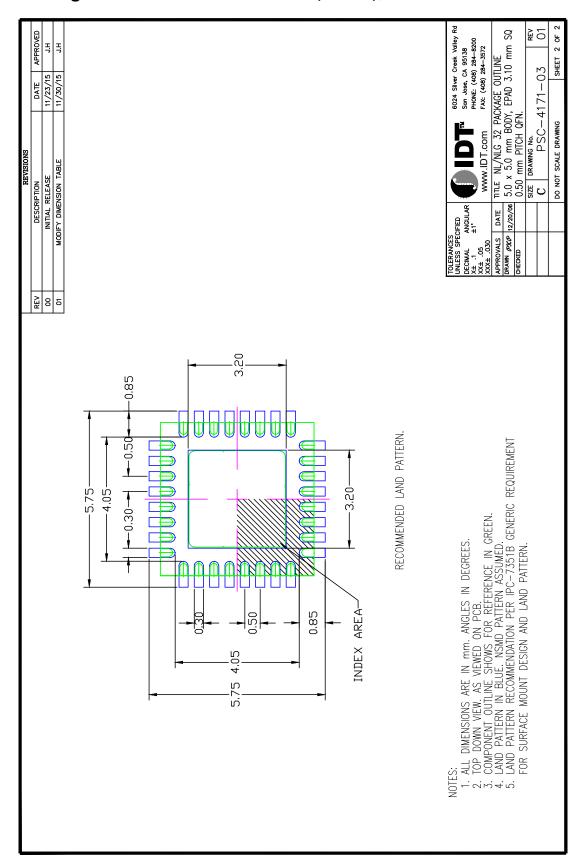


Package Outline and Dimensions (NLG32)





Package Outline and Dimensions (NLG32), cont.





Ordering Information

Part / Order Number	Notes	Shipping Packaging	Package	Temperature
9DBL0442BKILF	100Ω	Trays	32-pin VFQFPN	-40 to +85° C
9DBL0442BKILFT	10022	Tape and Reel	32-pin VFQFPN	-40 to +85° C
9DBL0452BKILF	85Ω	Trays	32-pin VFQFPN	-40 to +85° C
9DBL0452BKILFT	0322	Tape and Reel	32-pin VFQFPN	-40 to +85° C
9DBL04P2BxxxKILF	Factory configurable. Contact IDT for	Trays	32-pin VFQFPN	-40 to +85° C
9DBL04P2BxxxKILFT	addtional information.	Tape and Reel	32-pin VFQFPN	-40 to +85° C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History

Rev.	Initiator	Issue Date	Description	Page #
А	RDW	5/31/2016	 Add PCIe G1-4 Common Clock and PCIe SRIS to electrical tables Update Electrical Tables to final Changed '1' value in Byte 0 to indicate "Pin Control" Stylistic update to block diagram Minor updates to SMBus registers 0 and 1 for Readability Front page text update for family consistency. Removed '000' code from ordering information, updated table. Minor corrections to Byte 1 [1:0] and Byte 11 [1:0] 	Various
В	RDW	6/14/2016	 Electrical Table and SMBus Updates/Corrections Release to final. 	Various
С	RDW	6/21/2016	1. Updated ESD from 2000V to 2500V	5
D	RDW	11/11/2016	1. Corrected pin 32 to indicate an internal pull down resistor, not a pull up resistor.	2, 3
Е	RDW	2/8/2017	Renamed datasheet to 9DBL0442 / 9DBL0452	Various

[&]quot;B" is the device revision designator (will not correlate with the datasheet revision).

[&]quot;xxx" is a unique factory assigned number to identify a particular default configuration.



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